查询FX50SMJ-06供应商

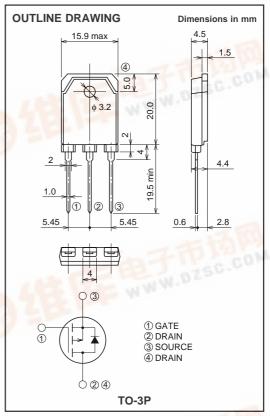
捷多邦,专业PCB打样工厂,24小时加急出货

MITSUBISHI Pch POWER MOSFET

FX50SMJ-06

HIGH-SPEED SWITCHING USE





APPLICATION

Motor control, Lamp control, Solenoid control DC-DC converter, etc.

MAXIMUM RATINGS (Tc = 25°C)

f.dzsc.com

| Symbol | Parameter | Conditions | Ratings | Unit |
|--------|----------------------------------|---------------|----------------------------|------|
| VDSS | Drain-source voltage | VGS = 0V | -60 | V |
| Vgss | Gate-source voltage | VDS = 0V | ±20 | V |
| ID | Drain current | CC COm | -50 | А |
| IDM | Drain current (Pulsed) | W.023 | -200 | А |
| IDA | Avalanche drain current (Pulsed) | L = 50μH | -50 | А |
| Is | Source current | | -50 | А |
| ISM | Source current (Pulsed) | | -200 | А |
| PD | Maximum power dissipation | | 150 | W |
| Tch | Channel temperature | | − 55 ~ + 150 | °C |
| Tstg | Storage temperature | | − 55 ~ + 150 | °C |
| | Weight | Typical value | 4.8 | g |





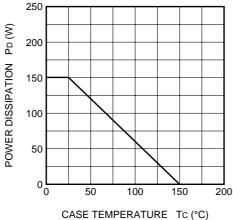
HIGH-SPEED SWITCHING USE

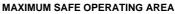
ELECTRICAL CHARACTERISTICS (Tch = 25°C)

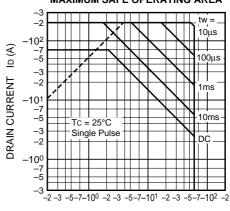
| Symbol | Parameter | Test conditions | Limits | | | Unit |
|------------|----------------------------------|---|--------|-------|-------|------|
| | | | Min. | Тур. | Max. | Onit |
| V (BR) DSS | Drain-source breakdown voltage | ID = -1mA, $VGS = 0V$ | -60 | _ | _ | V |
| Igss | Gate-source leakage current | $VGS = \pm 20V$, $VDS = 0V$ | _ | _ | ±0.1 | μΑ |
| IDSS | Drain-source leakage current | VDS = -60V, VGS = 0V | _ | _ | -0.1 | mA |
| VGS (th) | Gate-source threshold voltage | ID = -1mA, $VDS = -10V$ | -1.3 | -1.8 | -2.3 | V |
| rDS (ON) | Drain-source on-state resistance | ID = -25A, VGS = -10V | _ | 15.0 | 18.9 | mΩ |
| rDS (ON) | Drain-source on-state resistance | ID = -25A, VGS = -4V | _ | 23 | 32 | mΩ |
| VDS (ON) | Drain-source on-state voltage | ID = -25A, VGS = -10V | _ | -0.38 | -0.47 | V |
| yfs | Forward transfer admittance | ID = -25A, VDS = -10V | _ | 49.1 | _ | S |
| Ciss | Input capacitance | VDS = -10V, VGS = 0V, f = 1MHz | _ | 11610 | _ | pF |
| Coss | Output capacitance | | _ | 1355 | _ | pF |
| Crss | Reverse transfer capacitance | | _ | 687 | _ | pF |
| td (on) | Turn-on delay time | VDD = -30V, ID = -25A, VGS = -10V, RGEN = RGS = 50Ω | _ | 73 | _ | ns |
| tr | Rise time | | _ | 137 | _ | ns |
| td (off) | Turn-off delay time | | _ | 822 | _ | ns |
| tf | Fall time | | _ | 320 | _ | ns |
| VsD | Source-drain voltage | Is = -25A, VGS = 0V | _ | -1.0 | -1.5 | V |
| Rth (ch-c) | Thermal resistance | Channel to case | _ | _ | 0.83 | °C/W |
| trr | Reverse recovery time | Is = -50A, dis/dt = 100A/μs | _ | 70 | _ | ns |

PERFORMANCE CURVES

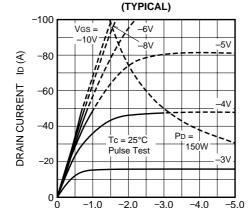
POWER DISSIPATION DERATING CURVE







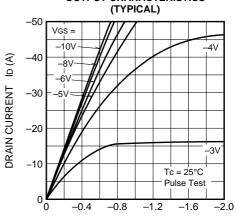
DRAIN-SOURCE VOLTAGE VDs (V)



DRAIN-SOURCE VOLTAGE VDS (V)

OUTPUT CHARACTERISTICS

OUTPUT CHARACTERISTICS

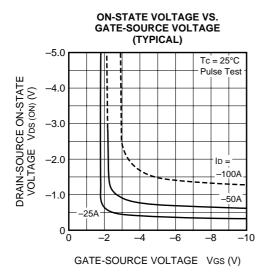


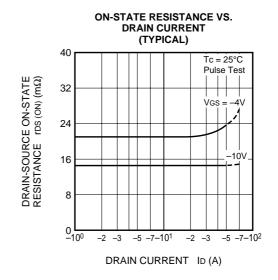
DRAIN-SOURCE VOLTAGE VDS (V)

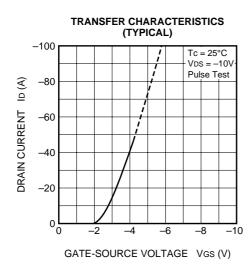


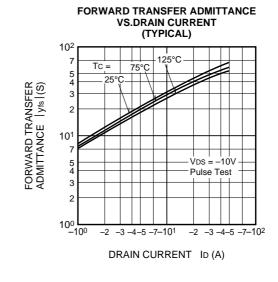


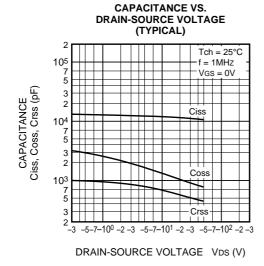
HIGH-SPEED SWITCHING USE

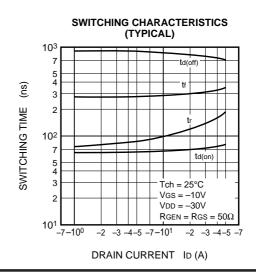
















HIGH-SPEED SWITCHING USE

